

# Product Specification

XBLW AO3401

P-Channel Enhancement Mode MOSFET

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## Description

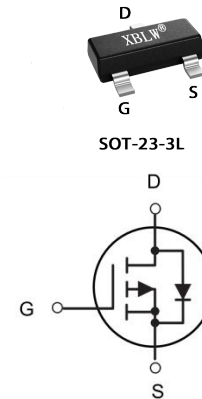
The AO3401 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

## General Features

- $V_{DS} = -30V$   $I_D = -4.2A$
- $R_{DS(ON)} < 54m\Omega @ V_{GS} = 10V$
- $R_{DS(ON)} < 77m\Omega @ V_{GS} = 4.5V$

## Application

- Battery protection
- Load switch
- Uninterruptible power supply



P-Channel MOSFET

## Package Marking and Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW AO3401	SOT-23-3L	X1KX	Tape	3000Pcs/Reel

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Limit	Unit
$V_{DS}$	Drain-Source Voltage	-30	V
$V_{GS}$	Gate-Source Voltage	$\pm 12$	V
$I_D$	Drain Current-Continuous	-4.2	A
$I_{DM}$	Drain Current-Pulsed (Note 1)	-30	A
$P_D$	Maximum Power Dissipation	1.2	W
$T_J, T_{STG}$	Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}C$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 2)	104	$^{\circ}C/W$

### Electrical Characteristics (TA=25°C unless otherwise noted)

Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-24V, V_{GS}=0V$	-	-	-1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 10V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>On Characteristics</b> (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.7	-1	-1.3	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=-10V, I_D=-4.2A$	-	46	54	m $\Omega$
		$V_{GS}=-4.5V, I_D=-4A$	-	58	77	m $\Omega$
		$V_{GS}=-2.5V, I_D=-1A$		74	130	m $\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS}=-5V, I_D=-4.2A$	-	10	-	S
<b>Dynamic Characteristics</b> (Note 4)						
Input Capacitance	$C_{iss}$	$V_{DS}=-15V, V_{GS}=0V,$ $F=1.0MHz$	-	880	-	PF
Output Capacitance	$C_{oss}$		-	105	-	PF
Reverse Transfer Capacitance	$C_{rss}$		-	65	-	PF
<b>Switching Characteristics</b> (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-15V, I_D=-4.2A$ $V_{GS}=-10V, R_{GEN}=6\Omega$	-	7	-	nS
Turn-on Rise Time	$t_r$		-	3	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	30	-	nS
Turn-Off Fall Time	$t_f$		-	12	-	nS
Total Gate Charge	$Q_g$	$V_{DS}=-15V, I_D=-4.2A, V_{GS}=-4.5V$	-	8.5	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.8	-	nC
Gate-Drain Charge	$Q_{gd}$		-	2.7	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$V_{SD}$	$V_{GS}=0V, I_S=-4.2A$	-	-	-1.2	V

**Notes:**

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

## Typical Electrical and Thermal Characteristics

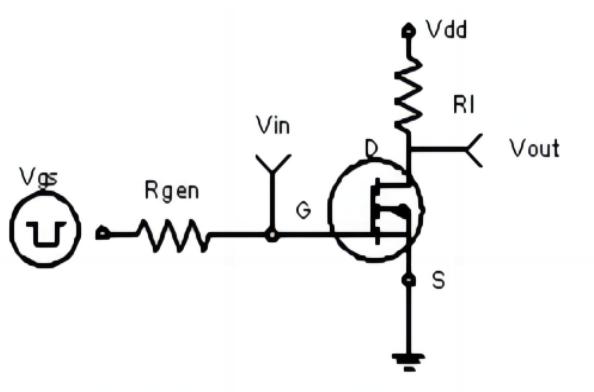


Figure 1: Switching Test Circuit

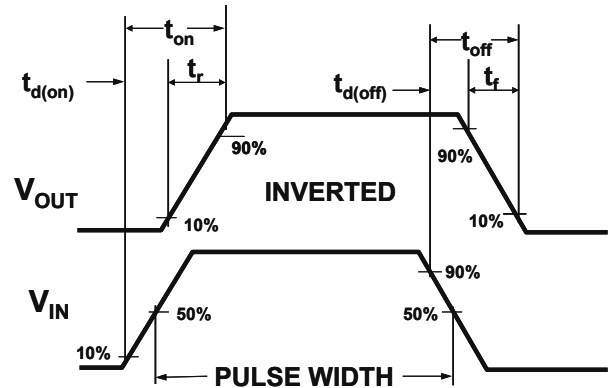
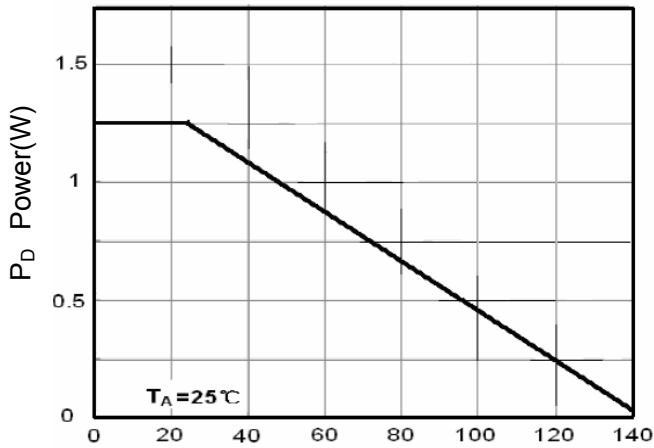
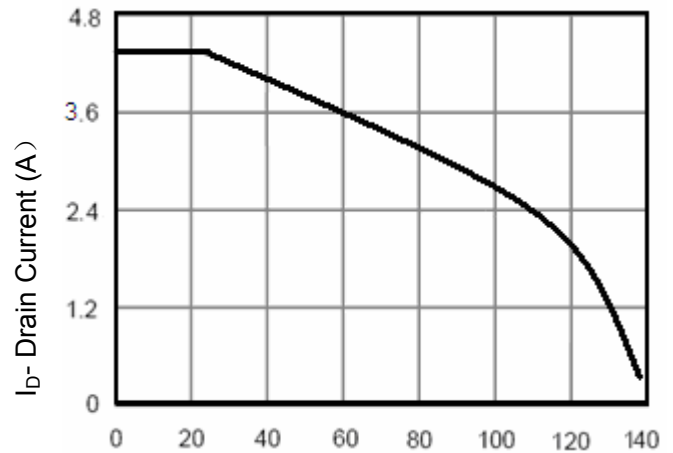


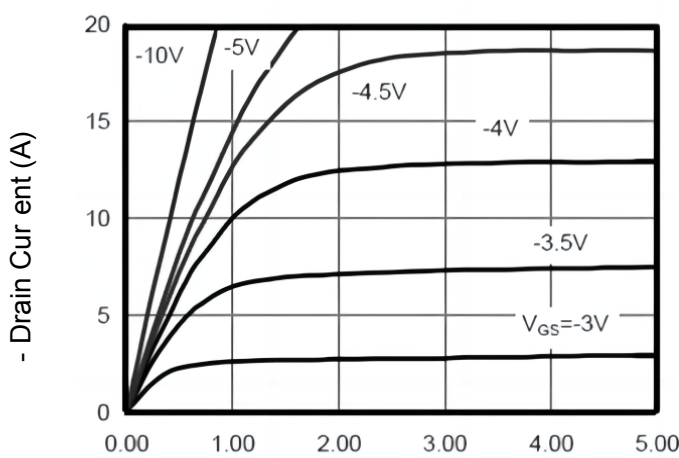
Figure 2: Switching Waveforms



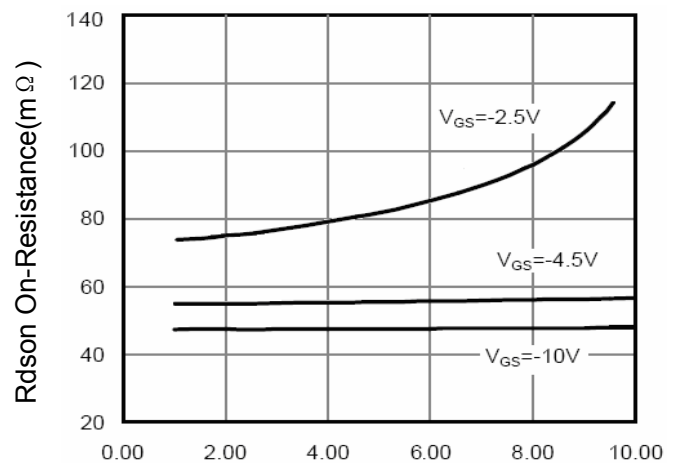
T<sub>J</sub>-Junction Temperature(°C)  
Figure 3 Power Dissipation



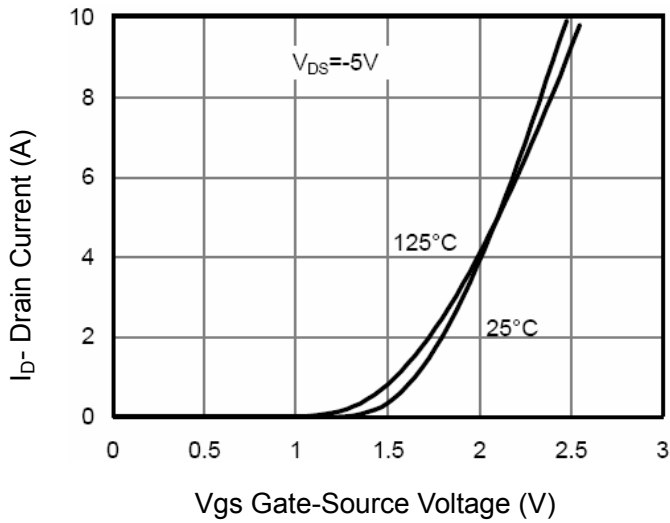
T<sub>J</sub>-Junction Temperature(°C)  
Figure 4 Drain Current



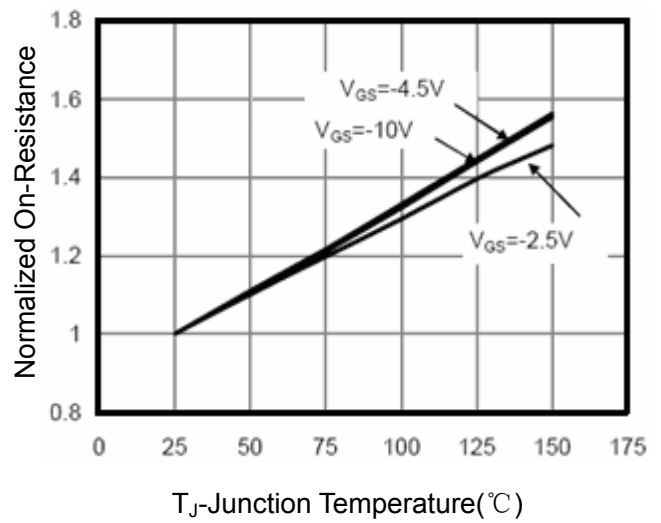
V<sub>ds</sub> Drain-Source Voltage (V)  
Figure 5 Output Characteristics



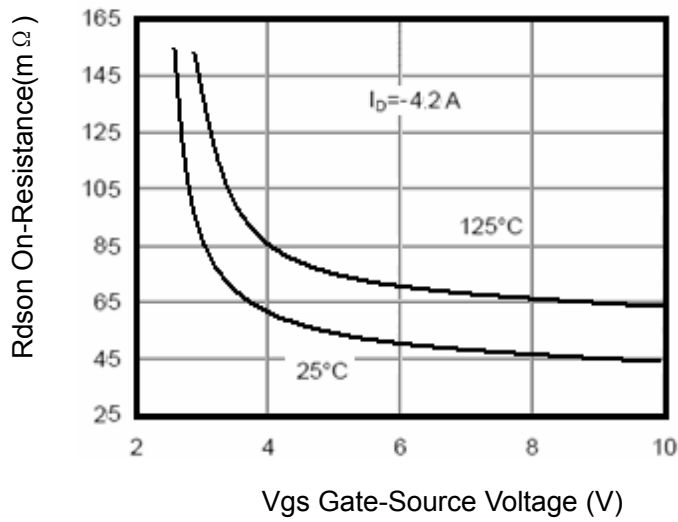
I<sub>D</sub>- Drain Current (A)  
Figure 6 Drain-Source On-Resistance



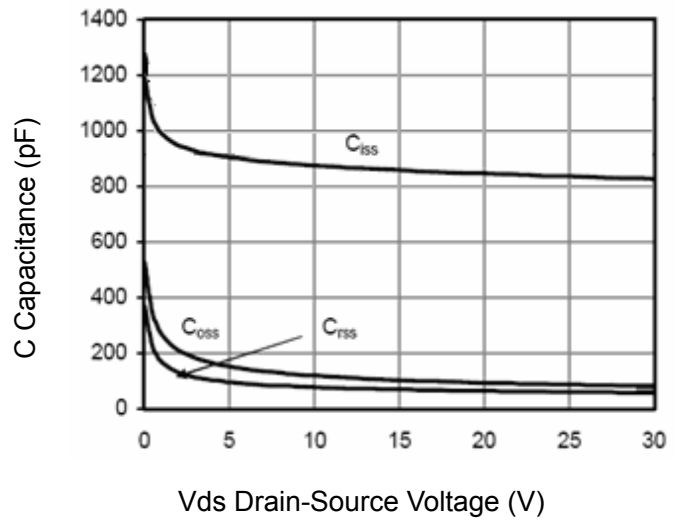
Vgs Gate-Source Voltage (V)  
Figure 7 Transfer Characteristics



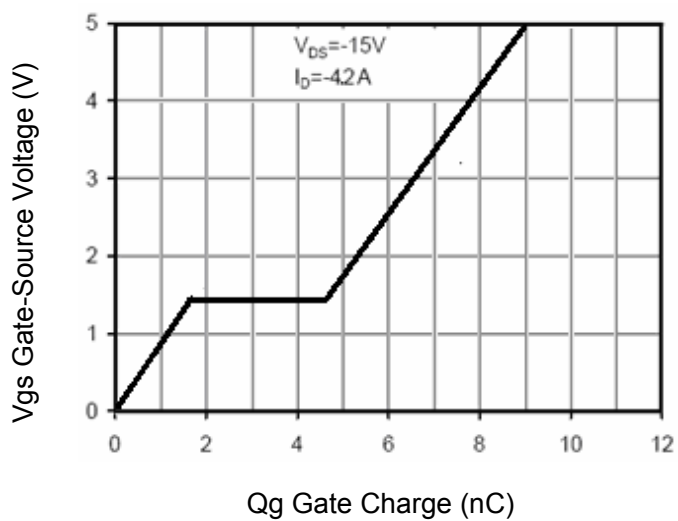
$T_J$ -Junction Temperature( $^\circ\text{C}$ )  
Figure 8 Drain-Source On-Resistance



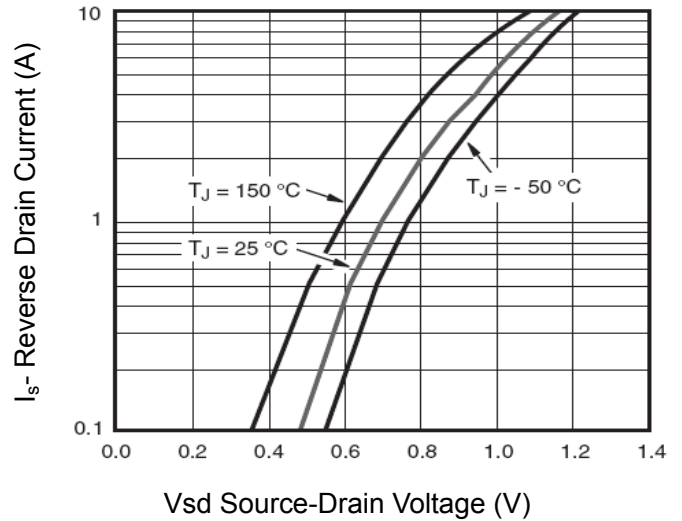
Vgs Gate-Source Voltage (V)  
Figure 9 Rdson vs Vgs



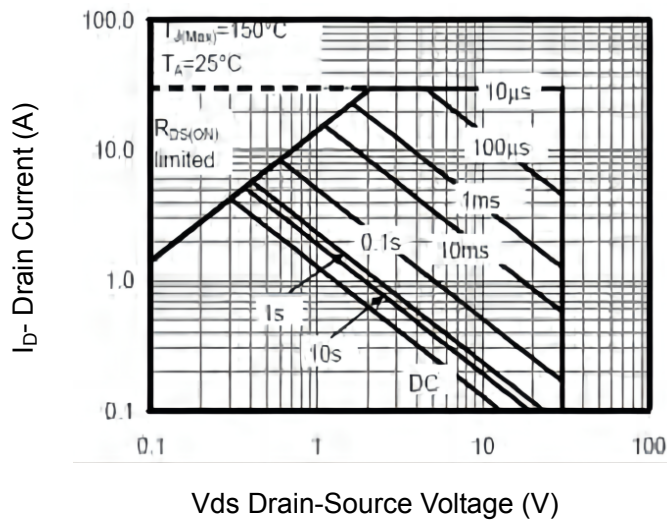
Vds Drain-Source Voltage (V)  
Figure 10 Capacitance vs Vds



Qg Gate Charge (nC)  
Figure 11 Gate Charge

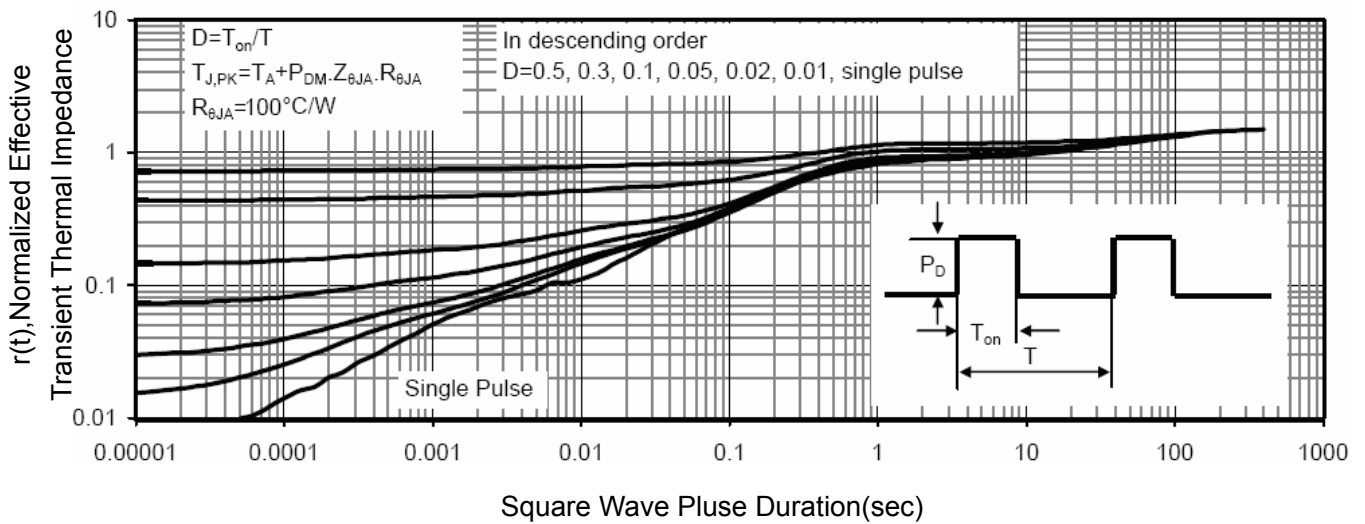


Vsd Source-Drain Voltage (V)  
Figure 12 Source- Drain Diode Forward



Vds Drain-Source Voltage (V)

Figure 13 Safe Operation Area

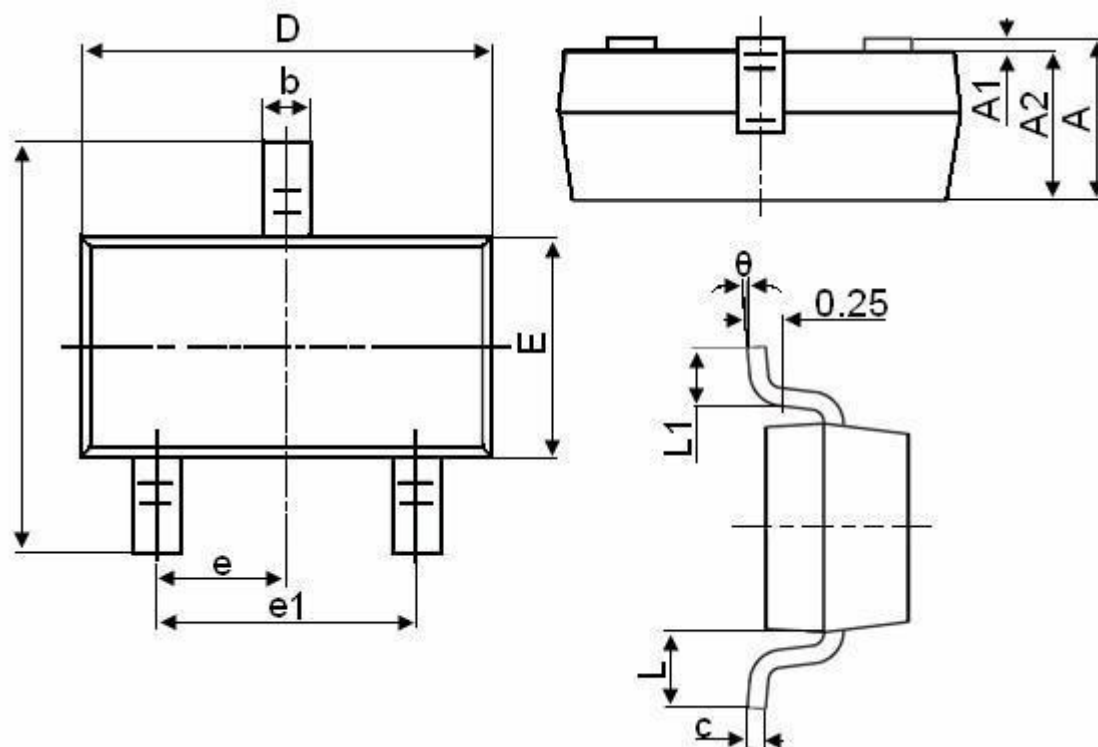


Square Wave Pluse Duration(sec)

Figure 14 Normalized Maximum Transient Thermal Impedance

## Package Information

SOT23-3L



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	1.050	1.250
A1	0.000	0.100
A2	1.050	1.150
b	0.300	0.500
c	0.100	0.200
D	2.800	3.000
E	1.500	1.700
E1	2.650	2.950
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.600
$\theta$	0°	8°

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